

**AMENDMENTS TO THE SPECIFICATION**

Please amend the Title of the Invention as follows:

SILICON CRYSTALLIZATION METHOD SEQUENTIAL LATERAL  
SOLIDIFICATION MASK WITH STRIPE-SHAPED PORTIONS FOR TRANSMITTING  
LASER LIGHT

Please amend the paragraph on page 2, above the heading BACKGROUND OF THE  
INVENTION as follows:

Cross-Reference To Related Applications

This application is a divisional application of U.S. Patent Application No.: 10/157,201  
filed May 30, 2002, now ~~allowed~~ U.S. Pat. No. 6,736,895; which claims priority to Korean  
Patent Application No.: 2001-30698, filed June 1, 2001, each of which is incorporated by  
reference for all purposes as if fully set forth herein.

Please DELETE paragraph [0001] as originally filed.